

DRDC3105

INTEGRATED RELAY, INDUCTIVE LOAD DRIVER

Description and Applications

The DRDC3105 is an integrated solid-state DC relay driver that can switch inductive loads. It provides a robust driver interface by acting as a buffer stage between sensitive logic circuits and that of 3 to 6V DC inductive relay coils. With a low input drive current requirement, the DRDC3105 only has slight loading on the input circuitry and it will provide good transient isolation between output and input channels. The output switch is guaranteed by design to go open-circuit and fall into the off-state condition when input drive is lost or disconnected.

In the industry standard SOT23 and SOT26, the DRDC3105 comes as a single or dual die which can replace three to six individual discrete components within a single integrated package, including a Zener across the output. The Zener will clamp at 6.6V to sink inductive currents to ground which will reduce EMI noise in the system. By integrating the Zener, the DRDC3105 eliminates the need for an external free-wheeling diode and allows the driving of inductive loads such as relays, solenoids, incandescent lamps, and small DC motors in:

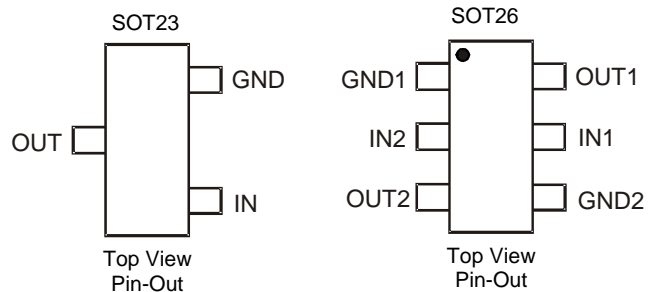
- Automotive: 5.0 V Driven Relays, Lamp Drivers, Motor Controls
- Telecom equipment: Modems, DSL, Cable (EMTA), Line Cards, IP-PBX, Analog Terminal Adaptors, End User Telecom Equipment
- Desktop Computers, Printers, Photocopiers
- LCD & Plasma TVs, Set Top Boxes
- Consumer Appliances, White Goods, Automated Door Control
- Industrial equipment inc. Process Control, ATE equipment
- Solar inverters

Features and Benefits

- Inductive load driver capable of driving 3 to 6V DC coils
- Optimized to switch inductive loads from supply of 3 to 5V with the capability to drive coils up to 2.5W from a 5V rail
- Fully integrated into a single SOT23 or dual SOT26 package to minimize footprint area and reduce number of components
- Includes Zener across output to reduce EMI noise
- Internal low saturation BJT to reduce power dissipation in driving high currents into the coil
- Output guaranteed to be in off-state condition during no input
- Near – Zero quiescent supply current in off-state condition with minimal leakage
- Rugged design and inherently robust by using solid-state BJT technology integrated into a single die
- ESD Protected up to 1kV on Human Body Model (HBM)**
- “Lead-Free”, RoHS Compliant (Note 1)**
- Halogen and Antimony Free “Green” Device (Note 2)**
- Qualified to AEC-Q101 Standards for High Reliability**

Mechanical Data

- Case: SOT23 & SOT26
- Case material: “Green” plastic molding compound (Note 2)
- UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Matte Tin Finish
- Weight: SOT23 = 0.008 grams (Approximate)
SOT26 = 0.018 grams (Approximate)

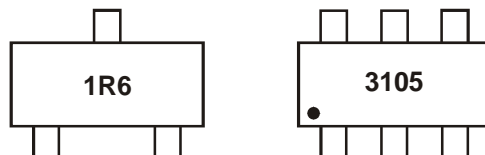


Ordering Information (Note 3)

Product	Package	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
DRDC3105F-7	SOT23	1R6	7	8	3,000
DRDC3105E6-7	SOT26	3105	7	8	3,000

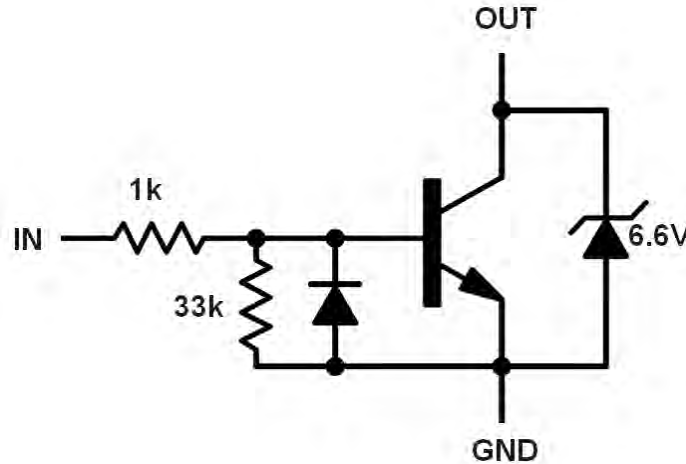
- Notes:
- No purposefully added lead.
 - Diodes Inc's "Green" policy can be found on our website at <http://www.diodes.com>
 - For packaging details, go to our website at <http://www.diodes.com>

Marking Information



1R6 = SOT23, Product type Marking Code
3105 = SOT26, Product type Marking Code

Internal Device Schematic



Maximum Ratings @ $T_A = 25^\circ\text{C}$ unless otherwise specified

Characteristic	Symbol	Limit	Unit
Supply Voltage	V_{CC}	6.0	V
Input Voltage (Forward)	$V_{in(fwd)}$	6.0	V
Input Voltage (Reverse)	$V_{in(rev)}$	-0.5	V
Output Sink Continuous Current (Note 4)	I_o	500	mA
Repetitive Pulse Zener Energy Limit (Duty Cycle 0.01%)	E_{zpk}	50	mJ

Thermal Characteristics for DRDC3105F (SOT23) @ $T_A = 25^\circ\text{C}$ unless otherwise specified

Characteristic	Symbol	Value	Unit
Power Dissipation (Note 4)	P_D	330	mW
Linear Derating Factor		2.64	mW/ $^\circ\text{C}$
Thermal Resistance, Junction to Ambient (Note 4)	$R_{\theta JA}$	379	$^\circ\text{C}/\text{W}$
Thermal Resistance, Junction to Case (Note 5)	$R_{\theta JC}$	306	$^\circ\text{C}/\text{W}$
Operating and Storage Temperature Range	T_J, T_{STG}	-55 to +150	$^\circ\text{C}$

- Notes: 4. For a device surface mounted on 25mm X 25mm X 1.6mm FR4 PCB with high coverage of single sided 1 oz copper, in still air condition; the device is measured when operating in a steady-state condition.
5. Thermal resistance from junction to case.

Thermal Characteristics for DRDC3105E6 (SOT26) @ $T_A = 25^\circ\text{C}$ unless otherwise specified

Characteristic	Symbol	Value	Unit
Power Dissipation Linear Derating Factor	P_D	0.9	W mW/ $^\circ\text{C}$
		7.2	
		1.1	
		8.8	
Thermal Resistance, Junction to Ambient	$R_{\theta JA}$	1.7	$^\circ\text{C}/\text{W}$
		13.6	
		139	
Thermal Resistance, Junction to Leads	$R_{\theta JL}$	113	$^\circ\text{C}/\text{W}$
		73	
Operating and Storage Temperature Range	T_J, T_{STG}	-55 to +150	$^\circ\text{C}$

- Notes: 6. For a device surface mounted on 25mm X 25mm FR4 PCB with high coverage of single sided 1 oz copper, in still air conditions
7. For a device surface mounted on FR4 PCB measured at < 5sec
8. Repetitive rating – pulse width limited by maximum junction temperature. Refer to transient thermal impedance graph
9. For a device with one active die
10. For a device with two die running at equal power
11. Thermal resistance from junction to solder-point (at the end of the "OUT" lead).

Electrical Characteristics @T_A = 25°C unless otherwise specified

Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition
OFF CHARACTERISTICS						
Output Zener Breakdown Voltage	BV _(out) BV _(-out)	6.2 -	6.6 0.67	7.0 -	V	@ IT = 10 mA Pulse
Output Leakage Current @ 0 Input Voltage	I _{OO}	- -	- -	0.1 30	μA	V _O = 5.5 V, T _A = 25°C V _O = 5.5 V, T _A = 85°C
“ON” state input voltage (Note 12)	V _{in(on)}		0.99	1.5	V	I _O = 100 mA, V _O = 150mV
“OFF” State Input Voltage (Note 13)	V _{in(off)}	400	540	-	mV	I _O = 100 μA, V _O = 4.9V
ON CHARACTERISTICS						
Input Bias Current (H _{FE} Limited)	I _{in}	-	0.7	1.6	mA	I _O = 250 mA, V _O = 0.25 V
Output Saturation Voltage	V _{O(sat)}	-	125	160	mV	I _O = 250 mA, I _{in} = 1.5 mA
Output Sink Current – Continuous	I _{O(on)}	250	430	-	mA	V _{CE} = 0.25 V, I _{in} = 1.5 mA
SWITCHING CHARACTERISTICS (Refer to Figure 1)						
Propagation Delay Times:						
High to Low Propagation Delay; (5.0V 74HC04)	t _{PHL}	-	20.4	-	ns	-
Low to High Propagation Delay; (5.0V 74HC04)	t _{PLH}	-	1.43	-	μs	-
High to Low Propagation Delay; 13 (3.0V 74HC04)	t _{PHL}	-	32.2	-	ns	-
Low to High Propagation Delay; 13 (3.0V 74HC04)	t _{PLH}	-	760	-	ns	-
High to Low Propagation Delay; 14 (5.0V 74LS04)	t _{PHL}	-	25.3	-	ns	-
Low to High Propagation Delay; 14 (5.0V 74LS04)	t _{PLH}	-	2.57	-	μs	-
Transition Times:						
Fall Time; (5.0V 74HC04)	t _f	-	12.5	-	ns	-
Rise Time; (5.0V 74HC04)	t _r	-	411	-	ns	-
Fall Time; 13 (3.0V 74HC04)	t _f	-	21.1	-	ns	-
Rise Time; 13 (3.0V 74HC04)	t _r	-	220	-	ns	-
Fall Time; 14 (5.0V 74LS04)	t _f	-	15.1	-	ns	-
Rise Time; 14 (5.0V 74LS04)	t _r	-	849	-	ns	-

Notes: 12. The device is guaranteed to be in “ON” state with V_{in(on)} above 1.5V
13. The device is guaranteed to be in “OFF” state with V_{in(off)} below 400mV

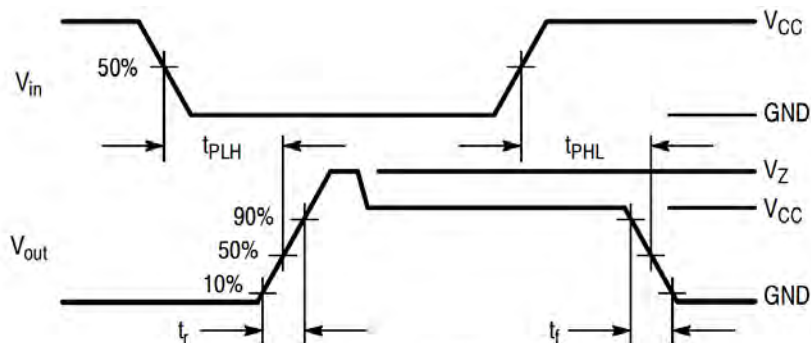


Figure 1. Switching Waveforms

Typical Electrical Characteristics

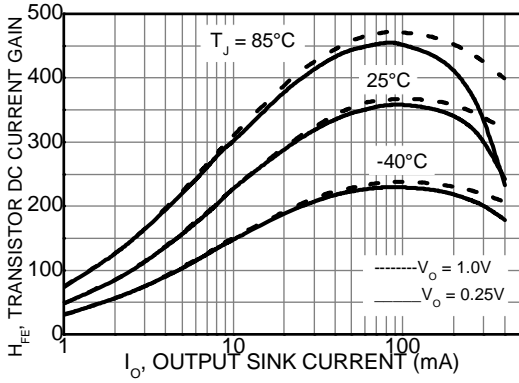


Figure 2. Transistor DC Current Gain

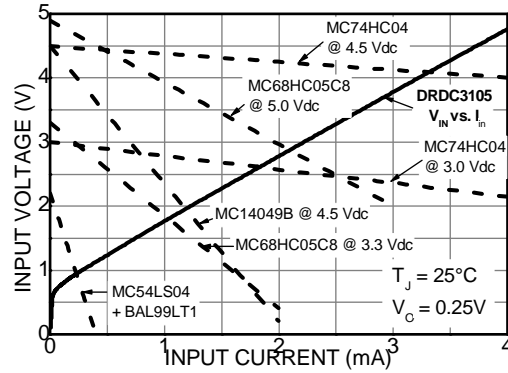


Figure 3. Input V-I Requirement Compared to Possible Source Logic Outputs

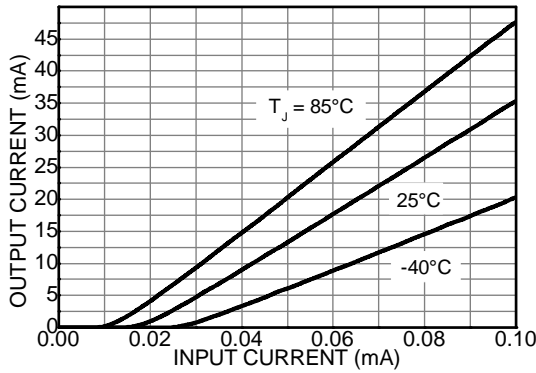


Figure 4. Threshold Effects

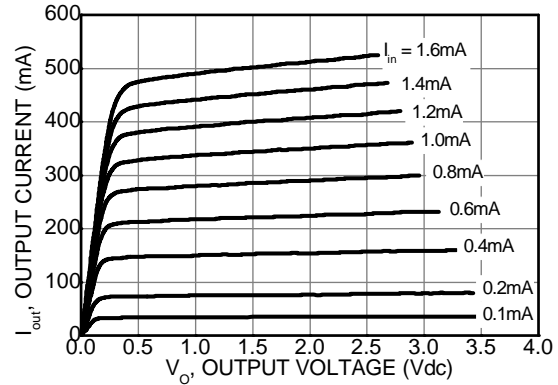


Figure 5. Transistor Output V-I Characteristic

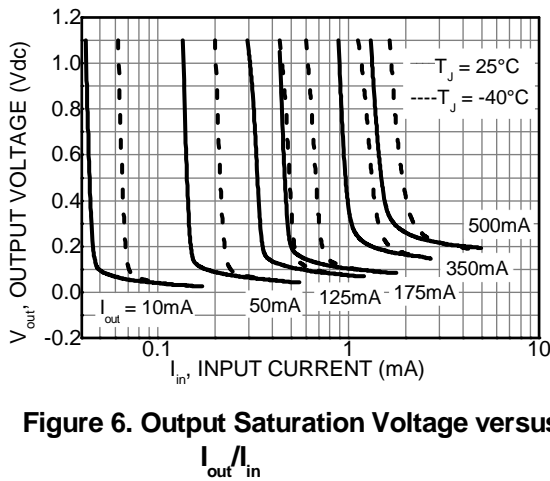


Figure 6. Output Saturation Voltage versus I_{out}/I_{in}

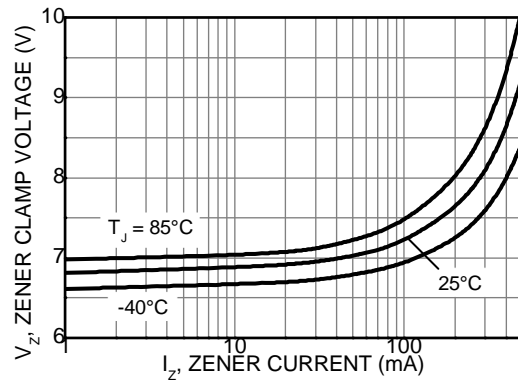


Figure 7. Zener Clamp Voltage versus Zener Current

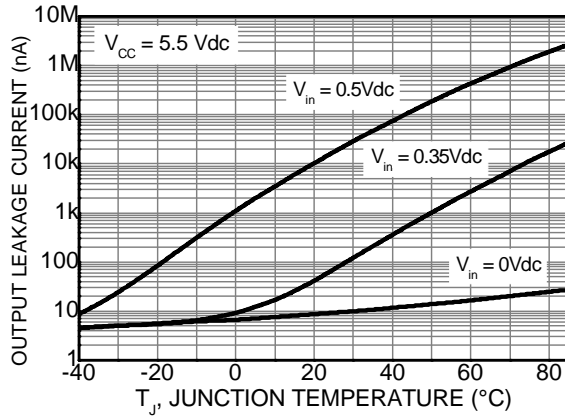


Figure 8. Output Leakage Current versus Temperature

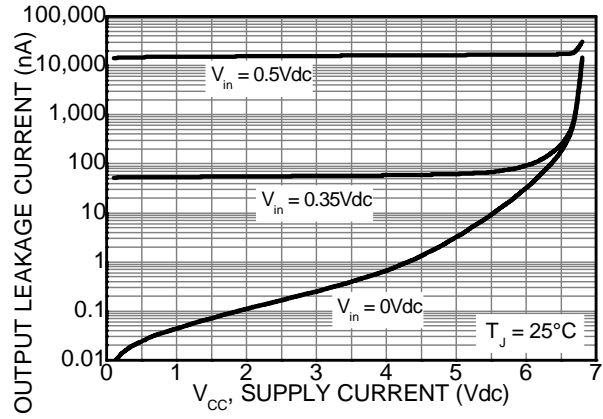


Figure 9. Output Leakage Current versus Supply Voltage

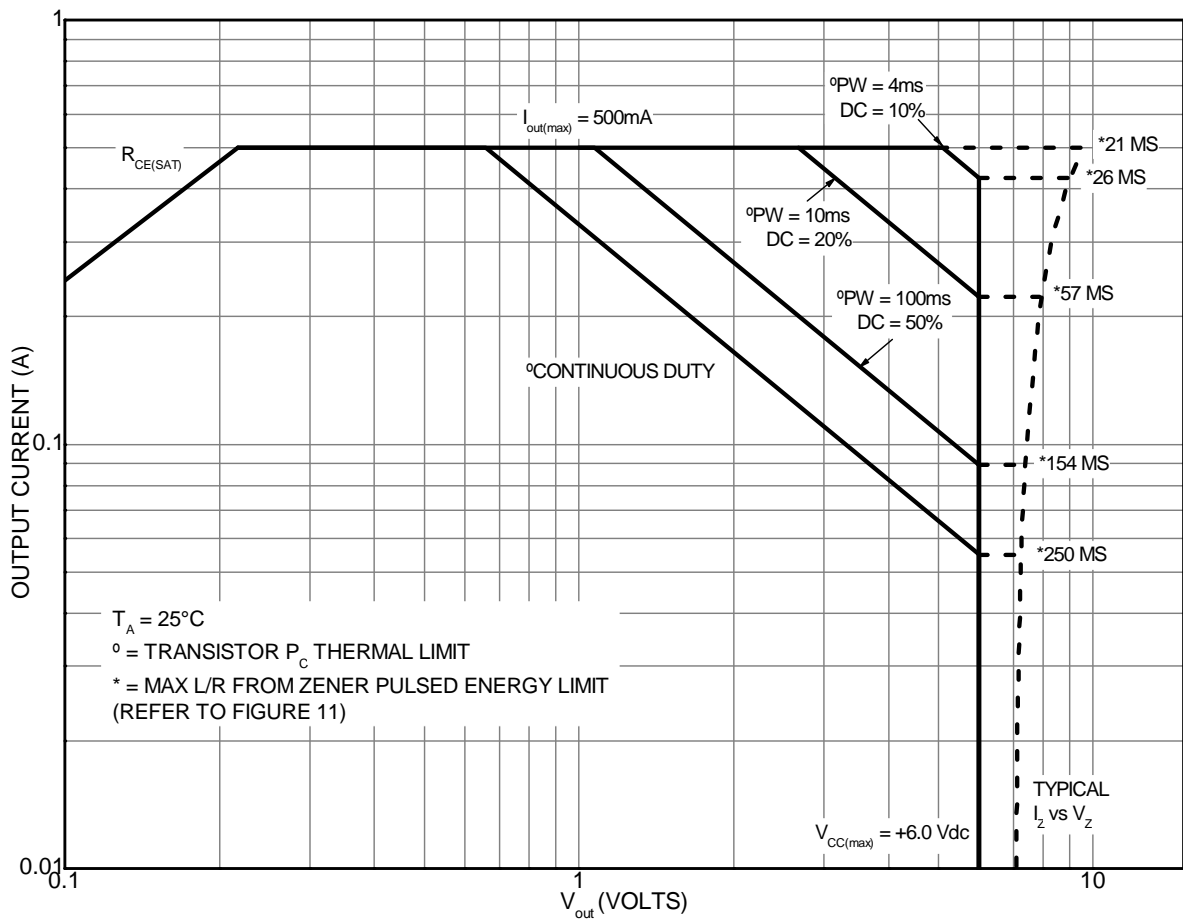


Figure 10. Safe Operating Area

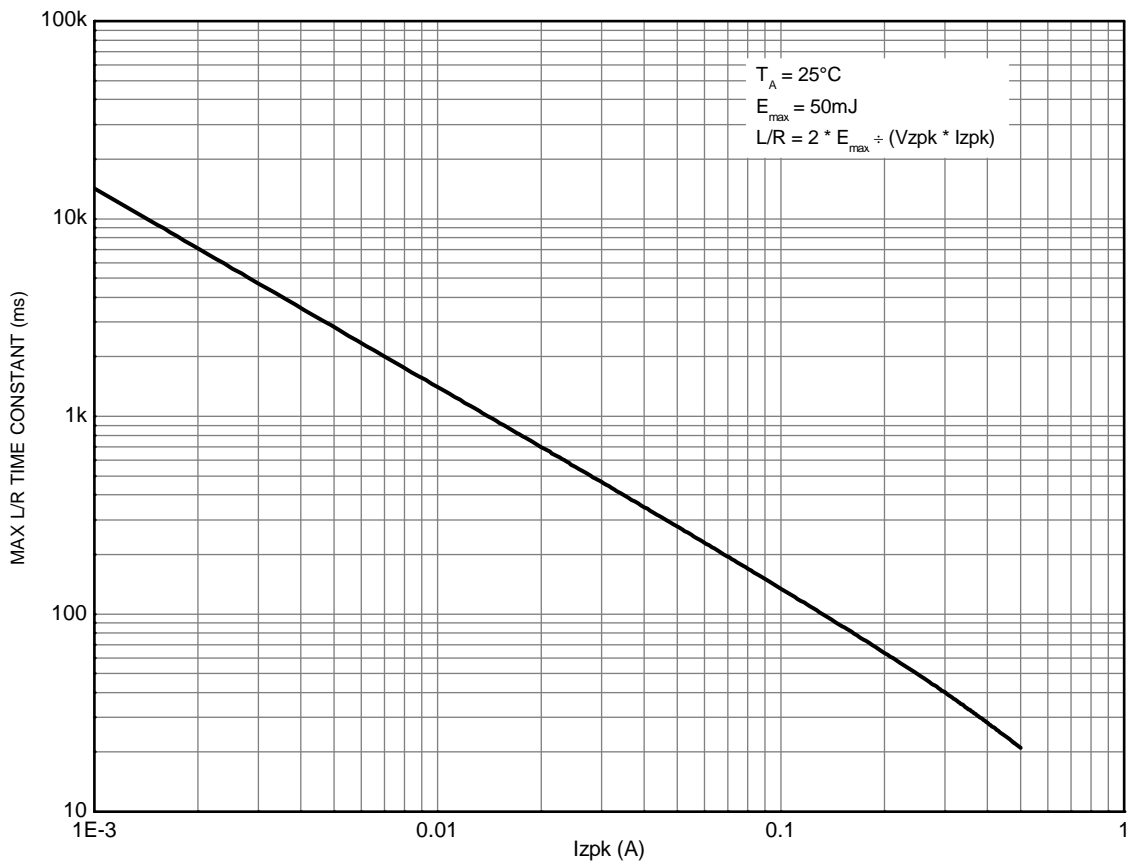


Figure 11. Zener Repetitive Pulse Energy Limit on L/R Time Constant

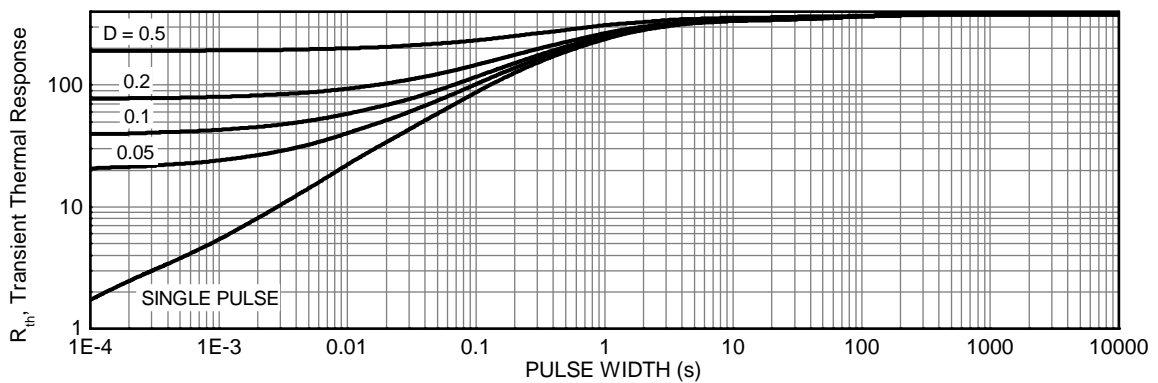
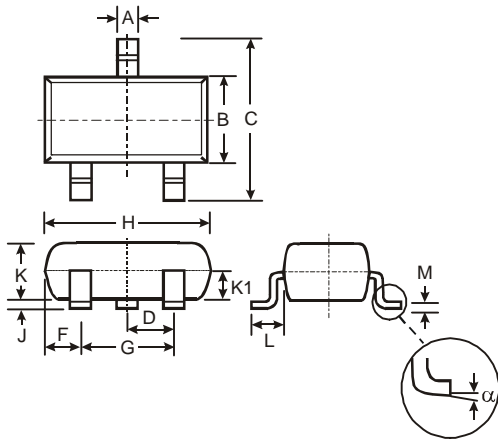


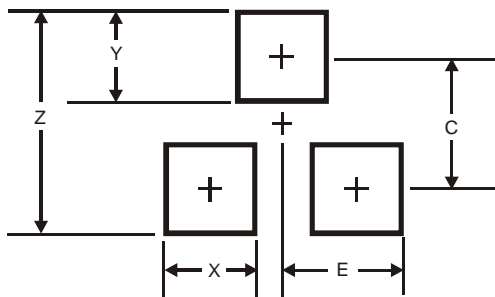
Figure 12. Transient Thermal Response

Package Outline Dimensions for SOT23



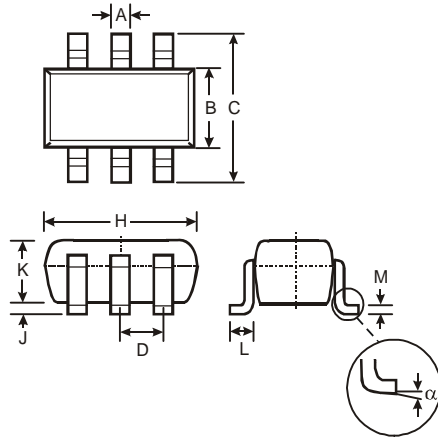
SOT23			
Dim	Min	Max	Typ
A	0.37	0.51	0.40
B	1.20	1.40	1.30
C	2.30	2.50	2.40
D	0.89	1.03	0.915
F	0.45	0.60	0.535
G	1.78	2.05	1.83
H	2.80	3.00	2.90
J	0.013	0.10	0.05
K	0.903	1.10	1.00
K1	-	-	0.400
L	0.45	0.61	0.55
M	0.085	0.18	0.11
α	0°	8°	-
All Dimensions in mm			

Suggested Pad Layout for SOT23



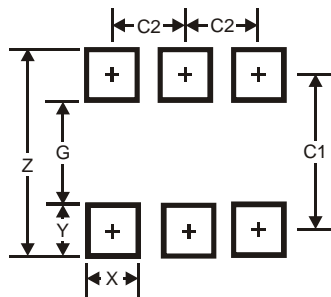
Dimensions	Value (in mm)
Z	2.9
X	0.8
Y	0.9
C	2.0
E	1.35

Package Outline Dimensions SOT26



SOT26			
Dim	Min	Max	Typ
A	0.35	0.50	0.38
B	1.50	1.70	1.60
C	2.70	3.00	2.80
D	—	—	0.95
H	2.90	3.10	3.00
J	0.013	0.10	0.05
K	1.00	1.30	1.10
L	0.35	0.55	0.40
M	0.10	0.20	0.15
α	0°	8°	—
All Dimensions in mm			

Suggested Pad Layout for SOT26



Dimensions	Value (in mm)
Z	3.20
G	1.60
X	0.55
Y	0.80
C1	2.40
C2	0.95

IMPORTANT NOTICE

DIODES INCORPORATED MAKES NO WARRANTY OF ANY KIND, EXPRESS OR IMPLIED, WITH REGARDS TO THIS DOCUMENT, INCLUDING, BUT NOT LIMITED TO, THE IMPLIED WARRANTIES OF MERCHANTABILITY AND FITNESS FOR A PARTICULAR PURPOSE (AND THEIR EQUIVALENTS UNDER THE LAWS OF ANY JURISDICTION).

Diodes Incorporated and its subsidiaries reserve the right to make modifications, enhancements, improvements, corrections or other changes without further notice to this document and any product described herein. Diodes Incorporated does not assume any liability arising out of the application or use of this document or any product described herein; neither does Diodes Incorporated convey any license under its patent or trademark rights, nor the rights of others. Any Customer or user of this document or products described herein in such applications shall assume all risks of such use and will agree to hold Diodes Incorporated and all the companies whose products are represented on Diodes Incorporated website, harmless against all damages.

Diodes Incorporated does not warrant or accept any liability whatsoever in respect of any products purchased through unauthorized sales channel. Should Customers purchase or use Diodes Incorporated products for any unintended or unauthorized application, Customers shall indemnify and hold Diodes Incorporated and its representatives harmless against all claims, damages, expenses, and attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized application.

Products described herein may be covered by one or more United States, international or foreign patents pending. Product names and markings noted herein may also be covered by one or more United States, international or foreign trademarks.

LIFE SUPPORT

Diodes Incorporated products are specifically not authorized for use as critical components in life support devices or systems without the express written approval of the Chief Executive Officer of Diodes Incorporated. As used herein:

A. Life support devices or systems are devices or systems which:

1. are intended to implant into the body, or
2. support or sustain life and whose failure to perform when properly used in accordance with instructions for use provided in the labeling can be reasonably expected to result in significant injury to the user.

B. A critical component is any component in a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or to affect its safety or effectiveness.

Customers represent that they have all necessary expertise in the safety and regulatory ramifications of their life support devices or systems, and acknowledge and agree that they are solely responsible for all legal, regulatory and safety-related requirements concerning their products and any use of Diodes Incorporated products in such safety-critical, life support devices or systems, notwithstanding any devices- or systems-related information or support that may be provided by Diodes Incorporated. Further, Customers must fully indemnify Diodes Incorporated and its representatives against any damages arising out of the use of Diodes Incorporated products in such safety-critical, life support devices or systems.

Copyright © 2011, Diodes Incorporated

www.diodes.com

Компания «Life Electronics» занимается поставками электронных компонентов импортного и отечественного производства от производителей и со складов крупных дистрибьюторов Европы, Америки и Азии.

С конца 2013 года компания активно расширяет линейку поставок компонентов по направлению коаксиальный кабель, кварцевые генераторы и конденсаторы (керамические, пленочные, электролитические), за счёт заключения дистрибьюторских договоров

Мы предлагаем:

- Конкурентоспособные цены и скидки постоянным клиентам.
- Специальные условия для постоянных клиентов.
- Подбор аналогов.
- Поставку компонентов в любых объемах, удовлетворяющих вашим потребностям.
- Приемлемые сроки поставки, возможна ускоренная поставка.
- Доставку товара в любую точку России и стран СНГ.
- Комплексную поставку.
- Работу по проектам и поставку образцов.
- Формирование склада под заказчика.
- Сертификаты соответствия на поставляемую продукцию (по желанию клиента).
- Тестирование поставляемой продукции.
- Поставку компонентов, требующих военную и космическую приемку.
- Входной контроль качества.
- Наличие сертификата ISO.

В составе нашей компании организован Конструкторский отдел, призванный помогать разработчикам, и инженерам.

Конструкторский отдел помогает осуществить:

- Регистрацию проекта у производителя компонентов.
- Техническую поддержку проекта.
- Защиту от снятия компонента с производства.
- Оценку стоимости проекта по компонентам.
- Изготовление тестовой платы монтаж и пусконаладочные работы.



Тел: +7 (812) 336 43 04 (многоканальный)

Email: org@lifeelectronics.ru